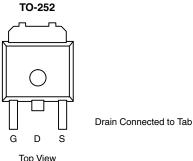


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N-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A) ^a		
30	0.0120 at V _{GS} = 10 V	17.5		
	0.0175 at V _{GS} = 4.5 V	14.5		



Top View

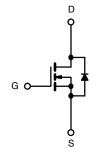
Ordering Information: SUD50N03-12P-E3 (Lead (PB) free)

FEATURES

- TrenchFET[®] Power MOSFET
 - 100 % R_g and UIS Tested



Compliant to RoHS Directive 2002/95/EC



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_A = 2$	25 °C, unless othe	rwise noted)			
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage	V _{GS}	± 20			
	T _A = 25 °C	L_	17.5		
Continuous Drain Current ^a	T _A = 100 °C	I _D	12.4	1	
Pulsed Drain Current	I _{DM}	40	А		
Continuous Source Current (Diode Conduction) ^a	۱ _S	5	-		
Avalanche Current L = 0.1 mH		I _{AS}			30
Single Pulse Avalanche Energy		E _{AS}	45	mJ	
Movimum Dower Dissinction	T _C = 25 °C	Р	46.8	- w	
Maximum Power Dissipation	T _A = 25 °C	P _D	6.5 ^a		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Mariana landian la Ambianta	t ≤ 10 s	- R _{thJA}	18	23	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		40	50		
Maximum Junction-to-Case		R _{thJC}	2.6	3.2		

Note: a. Surface mounted on FR4 board, t \leq 10 s.

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Parameter	Symbol	Test Conditions	Min .	Typ. ^a	Max.	Unit
Static					<u> </u>	
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	30			V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	1		3	v
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	1= = =	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	
Zero Gale voltage Drain Current	IDSS	$V_{DS} = 24 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$			50	μA
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	40			Α
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	0.0100		0.0120	
Drain-Source On-State Resistance ^b	R _{DS(on)}	V_{GS} = 10 V, I_{D} = 20 A, T_{J} = 125 °C			0.0170	
		V _{GS} = 4.5 V, I _D = 15 A		0.0138	0.0175	
Forward Transconductance ^b	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	15			S
Dynamic ^a						
Input Capacitance	C _{iss}			1600		pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$, $V_{DS} = 25 V$, f = 1 MHz		285		
Reverse Transfer Capacitance	C _{rss}			140		
Total Gate Charge ^c	Qg			28	42	
Gate-Source Charge ^c	Q _{gs}	V_{DS} = 15 V, V_{GS} = 10 V, I_{D} = 50 A		6		nC
Gate-Drain Charge ^c	Q _{gd}			5		
Gate Resistance	Rg	f = 1 MHz	0.3	1.5	3.0	Ω
Turn-On Delay Time ^c	t _{d(on)}			9	15	
Rise Time ^c	t _r	V_{DD} = 15 V, R_L = 0.3 Ω		15	25	20
Turn-Off Delay Time ^c	t _{d(off)}	$\text{I}_\text{D} \cong$ 50 A, V_GEN = 10 V, R_G = 2.5 Ω		20	30	ns
Fall Time ^c	t _f			12	20	
Source-Drain Diode Ratings and Char	acteristics (T	_C = 25 °C)				
Pulsed Current	I _{SM}				100	Α
Diode Forward Voltage ^b	V _{SD}	I _F = 40 A, V _{GS} = 0 V		1.2	1.5	V
Source-Drain Reverse Recovery Time	t _{rr}	I _E = 50 A, dl/dt = 100 A/μs		25	70	ns

Notes:

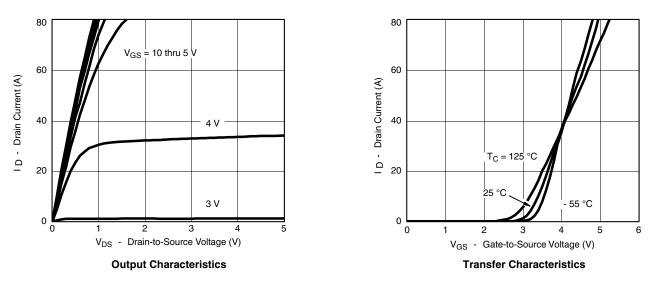
a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C unless noted)



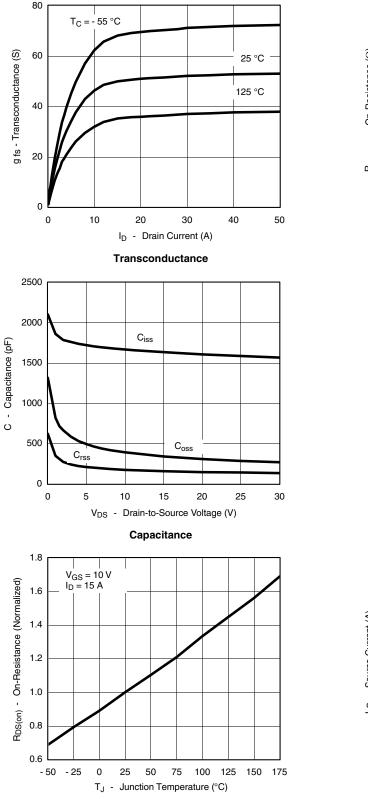
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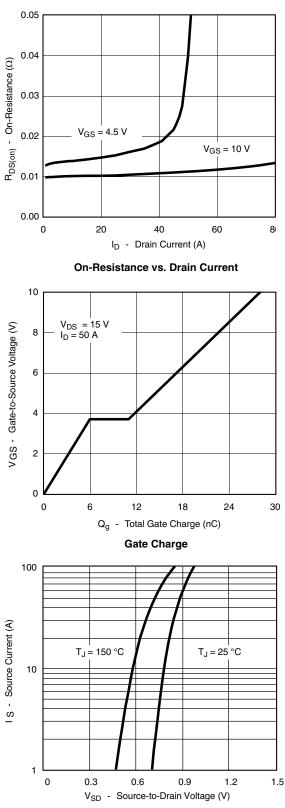


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TYPICAL CHARACTERISTICS (25 °C unless noted)



On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage

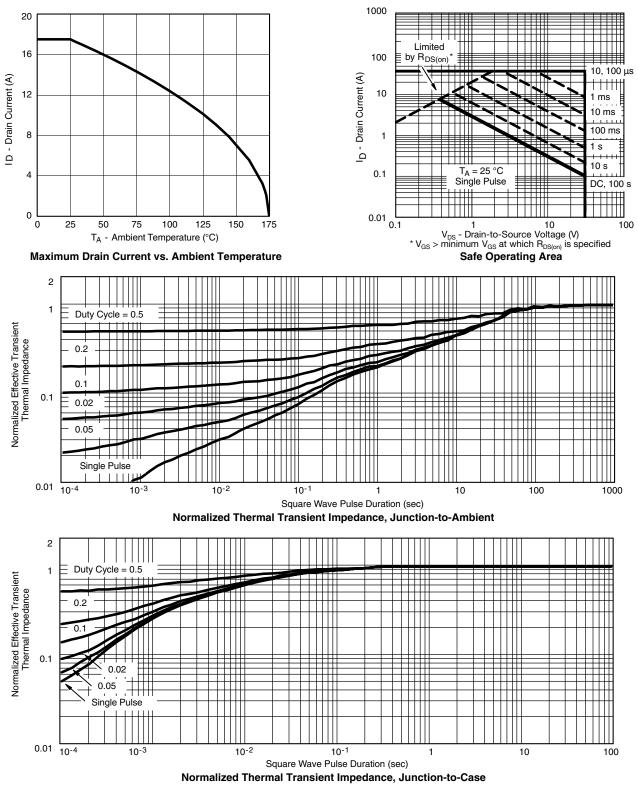
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THERMAL RATINGS



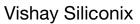
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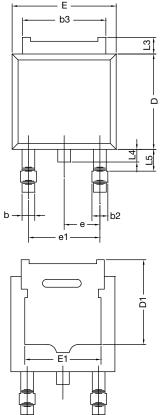
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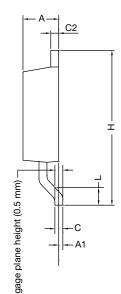
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TO-252AA Case Outline





	MILLIN	IETERS	TERS INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	4.10	-	0.161	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090 BSC		
e1	4.56	4.56 BSC 0.180) BSC	
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.01	1.52	0.040	0.060	
ECN: T16- DWG: 534	0236-Rev. P, ⁻ 7	16-May-16			

Notes

• Dimension L3 is for reference only.



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RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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